# NSN 5961-01-306-8849

Semiconductor Device Set - Page 1 of 1



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Inc	losure	Mate	rial:

Glass all semiconductor device diode

### **Overall Length:**

0.170 inches all semiconductor device diode

### **Terminal Length:**

1.000 inches all semiconductor device diode

#### **Overall Diameter:**

0.191 inches all semiconductor device diode

### **Function For Which Designed:**

General purpose

### **Internal Configuration:**

Junction contact all semiconductor device diode

### **Internal Junction Configuration:**

Pn all semiconductor device diode

#### **Component Function Relationship:**

Matched

# **Component Name And Quantity:**

2 semiconductor device diode

# **Mounting Method:**

Terminal all semiconductor device diode

### **Features Provided:**

Hermetically sealed case

# **Semiconductor Material:**

Silicon all semiconductor device diode

## Voltage Rating In Volts Per Characteristic:

340.0 forward voltage, dc all semiconductor device diode

### **Current Rating Per Characteristic:**

10.00 milliamperes source cutoff current preset all semiconductor device diode

### **Power Rating Per Characteristic:**

150.0 milliwatts small-signal input power, common-collector preset all semiconductor device diode

# **Maximum Operating Tempurature Per Measurement Point:**

150.0 degrees celsius ambient air all semiconductor device diode

### **Terminal Type And Quantity:**

2 uninsulated wire lead all semiconductor device diode

### Shelf Life:

N/a

### **Unit Of Measure:**

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# Demilitarization:

No

### Fiig:

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